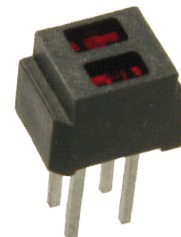


# Reflective Object Sensor

OPB606A, OPB606B, OPB606C

OPB607A, OPB607B, OPB607C



## Features:

- Choice of phototransistor (OPB606) or photodarlington (OPB607) output
- Unfocused for sensing diffuse surface
- Low cost plastic housing
- Filtered (OPB606, OPB607)

## Description:

**OPB606** consists of an infrared Light Emitting Diode (LED) and an NPN silicon phototransistor which are mounted “side-by-side” on parallel axes in a black opaque plastic housing.

The **OPB607** consists of an infrared Light Emitting Diode (LED) and an NPN silicon photodarlington which are mounted “side-by-side” on parallel axes in a black plastic housing.

The emitting diode and phototransistor of both the **OPB606** and **OPB607** are encapsulated in a filtering epoxy that reduces ambient light noise. On both models, the phototransistors respond to radiation from the emitter only when a reflective object passes within the field of view.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

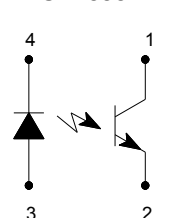
## Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

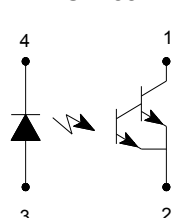
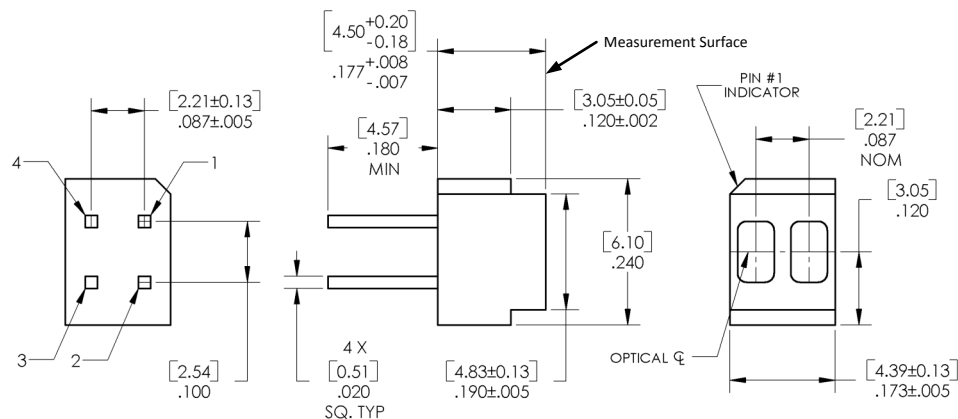
| Pin # | LED     | Pin # | Transistor |
|-------|---------|-------|------------|
| 4     | Cathode | 1     | Collector  |
| 3     | Anode   | 2     | Emitter    |

| Ordering Information |                     |            |                                       |             |
|----------------------|---------------------|------------|---------------------------------------|-------------|
| Part Number          | LED Peak Wavelength | Sensor     | Typical Reflection Distance Inch (mm) | Lead Length |
| OPB606A              | 935 nm              | Transistor | 0.050" (1.27mm)                       | 0.18" (Min) |
| OPB606B              |                     |            |                                       |             |
| OPB606C              |                     |            |                                       |             |
| OPB607A              |                     | Darlington |                                       |             |
| OPB607B              |                     |            |                                       |             |
| OPB607C              |                     |            |                                       |             |

OPB606



OPB607



DIMENSIONS ARE IN: [ MILLIMETERS ]  
[ INCHES ]

### CONTAINS POLYSULFONE

To avoid stress cracking, we suggest using ND Industries' **Vibra-Tite** for thread-locking. **Vibra-Tite** evaporates fast without causing structural failure in OPTEK's molded plastics.

## General Note

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# Reflective Object Sensor

OPB606A, OPB606B, OPB606C

OPB607A, OPB607B, OPB607C



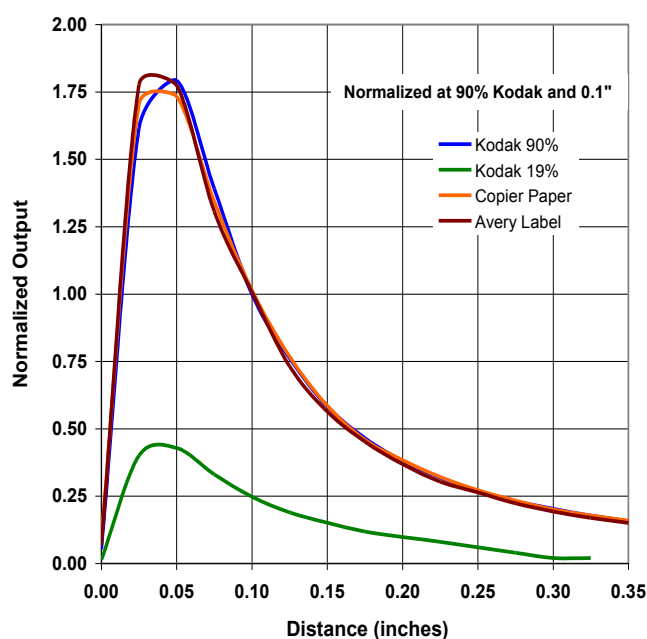
## Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

|                                                                                                             |                  |
|-------------------------------------------------------------------------------------------------------------|------------------|
| Storage & Operating Temperature Range                                                                       | -40° C to +85° C |
| Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron] <sup>(1)</sup> | 260° C           |
| <b>Input Diode</b>                                                                                          |                  |
| Forward DC Current                                                                                          | 50 mA            |
| Peak Forward Current (1 $\mu\text{s}$ pulse width, 300 pps)                                                 | 3 A              |
| Reverse DC Voltage                                                                                          | 2 V              |
| Power Dissipation <sup>(2)</sup>                                                                            | 75 mW            |
| <b>Output Phototransistor (OPB606) / Output Photodarlington (OPB607)</b>                                    |                  |
| Collector-Emitter Voltage<br>OPB606A, OPB606B, OPB606C<br>OPB607A, OPB607B, OPB607C                         | 30 V<br>15 V     |
| Emitter-Collector Voltage                                                                                   | 5 V              |
| Collector DC Current<br>OPB606A, OPB606B, OPB606C<br>OPB607A, OPB607B, OPB607C                              | 25 mA<br>125 mA  |
| Power Dissipation <sup>(2)</sup>                                                                            | 75 mW            |

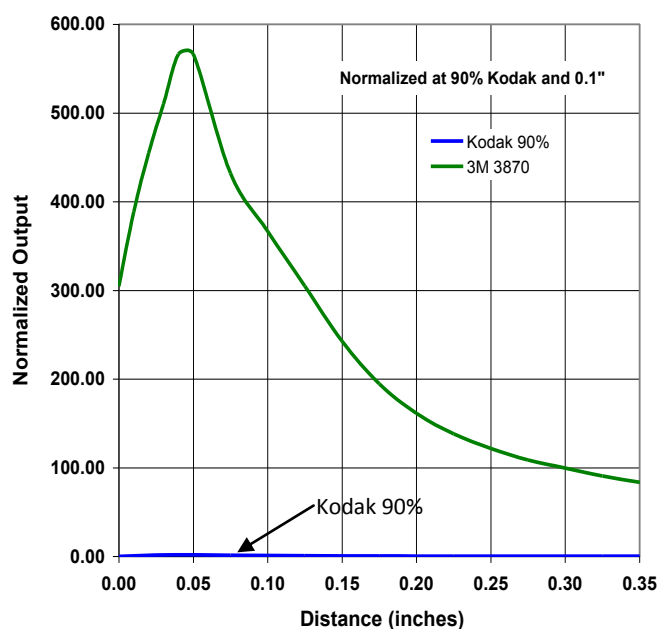
Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly 1.25 mW/°C above 25° C.

OPB606 - Output vs Distance



OPB606 - Output vs Distance (Retro)



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# Reflective Object Sensor

OPB606A, OPB606B, OPB606C

OPB607A, OPB607B, OPB607C

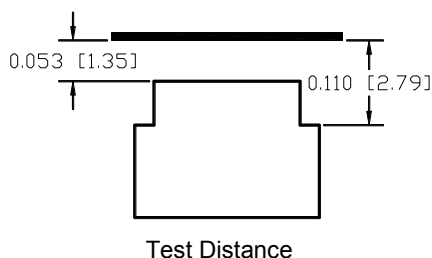


## Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| SYMBOL                                                                                  | PARAMETER                                                                                    | MIN                                 | TYP                        | MAX                        | UNITS                            | TEST CONDITIONS                                                                                                                                                                  |
|-----------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------|-------------------------------------|----------------------------|----------------------------|----------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>Input Diode</b> (See OP165 for additional information)                               |                                                                                              |                                     |                            |                            |                                  |                                                                                                                                                                                  |
| V <sub>F</sub>                                                                          | Forward Voltage                                                                              | -                                   | -                          | 1.7                        | V                                | I <sub>F</sub> = 20 mA                                                                                                                                                           |
| I <sub>R</sub>                                                                          | Reverse Current                                                                              | -                                   | -                          | 100                        | μA                               | V <sub>R</sub> = 2 V                                                                                                                                                             |
| <b>Output Phototransistor</b> (see OP268 for additional information—for reference only) |                                                                                              |                                     |                            |                            |                                  |                                                                                                                                                                                  |
| V <sub>(BR)CEO</sub>                                                                    | Collector-Emitter Breakdown Voltage<br>OPB606<br>OPB607                                      | 30<br>15                            | -<br>-                     | -<br>-                     | V<br>V                           | I <sub>C</sub> = 100 μA                                                                                                                                                          |
| V <sub>(BR)ECO</sub>                                                                    | Emitter-Collector Breakdown Voltage                                                          | 5                                   | -                          | -                          | V                                | I <sub>E</sub> = 100 μA                                                                                                                                                          |
| I <sub>CEO</sub>                                                                        | Collector Dark Current<br>OPB606<br>OPB607                                                   | -<br>-                              | -<br>-                     | 100<br>250                 | nA<br>nA                         | V <sub>CE</sub> = 5 V, I <sub>F</sub> = 0                                                                                                                                        |
| <b>Combined</b> (see OP508 or OP509 for additional information—for reference only)      |                                                                                              |                                     |                            |                            |                                  |                                                                                                                                                                                  |
| V <sub>CE(SAT)</sub>                                                                    | Collector-Emitter Saturation Voltage<br><br>OPB606<br>OPB607                                 | -<br>-                              | -<br>-                     | 0.4<br>1.1                 | V                                | I <sub>F</sub> = 20 mA, I <sub>C</sub> = 100 μA, d = 0.053" (1.45 mm) <sup>(1)(2)</sup><br>I <sub>F</sub> = 20 mA, I <sub>C</sub> = 2 mA, d = 0.053" (1.45 mm) <sup>(1)(2)</sup> |
| I <sub>C(ON)</sub>                                                                      | On-State Collector Current<br>OPB606A<br>OPB606B<br>OPB606C<br>OPB607A<br>OPB607B<br>OPB607C | 500<br>350<br>200<br>25<br>17<br>10 | -<br>-<br>-<br>-<br>-<br>- | -<br>-<br>-<br>-<br>-<br>- | μA<br>μA<br>μA<br>mA<br>mA<br>mA | I <sub>F</sub> = 20 mA, V <sub>ce</sub> = 5 V, d = 0.053" (1.45 mm) <sup>(1)(2)</sup>                                                                                            |
| I <sub>C(OFF)</sub>                                                                     | Off-State Collector Current<br>OPB606<br>OPB607                                              | -<br>-                              | -<br>-                     | 200<br>10                  | nA<br>μA                         | V <sub>CE</sub> = 5 V, I <sub>F</sub> = 20 mA <sup>(3)</sup><br>V <sub>CE</sub> = 5 V, I <sub>F</sub> = 20 mA <sup>(3)</sup>                                                     |

### Notes:

- (1) "d" is the distance from the assembly measurement surface to the reflective surface.
- (2) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (3) On OPB606, off-state collector current  $I_{C(OFF)}$  is measured with no reflective surface in the optical path. On OPB607, Crosstalk ( $I_{CX}$ ) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (4) All parameters tested using pulse techniques.



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